



8A SILICON CARBIDE SCHOTTKY DIODE

Product Summary

V _{RRM} (V)	lo (A)	V _F (Max) (V) @ +25°C	I _R (Typ) (μA) @ +25°C	
650	8	1.7	0.9	

Description and Applications

Packaged in the robust industry-standard TO220AC (Type WX) package, the DIODES™ DSC08C065 provides excellent reverse leakage stability at high temperatures. It is ideal for use as a rectifier, freewheel diode, or blocking diode in:

- Power factor correction
- Industrial motor drivers
- Power inverters
- SMPS
- UPS

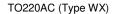
Features and Benefits

- Low Conduction and Switching Loss
- High Temperature Application
- Positive Temperature Coefficient on V_F
- Fast Reverse Recovery
- High Surge Current Capability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

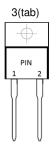
Mechanical Data

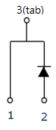
- Package: TO220AC
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Weight: 1.868 grams (Approximate)





Top View





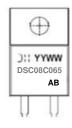
Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Number	rackaye	Qty.	Carrier	
DSC08C065	TO220AC (Type WX)	50 Pieces	Tube	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



DIII = Manufacturer's Marking
DSC08C065 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 23 = 2023)
WW = Week (01 to 53)
AB = Foundry and Assembly Code



Maximum Ratings (@ $T_C = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Surge Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{DC}	650	V
Average Rectified Output Current	lo	8	Α
Non-Repetitive Peak Forward Surge Current 10ms Half Sine Wave Form	IFSM	38	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Notes 5, 6 & 7)	Rejc	4	°C/W
Typical Thermal Resistance, Junction to Lead (Notes 5, 6 & 7)	$R_{ heta JL}$	3	°C/W
Operating and Storage Temperature Range	T_{J}, T_{STG}	-55 to +175	°C

Notes:

- 5. Thermal resistance test performed in accordance with JESD-51.
- 6. Rating with heatsink 75mm x 75mm x 2mm.
- 7. Device mounted on 1inch² copper pad, 2oz. The heat generated must be less than the thermal conductivity from junction to case: $dP_D/dT_J < 1/R_{\theta JC}$ or junction to ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

Electrical Characteristics (@ T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Voltage	V_{BR}	650	_	_	V	$I_R = 0.1 \text{mA}$
Forward Voltage Drop	VF		1.46 1.97	1.7 2.5	V	I _F = 8A, T _J = +25°C I _F = 8A, T _J = +175°C
Leakage Current	I _R		0.9 108	200 —	μΑ	V _R = 650V, T _J = +25°C V _R = 650V, T _J = +175°C
Total Capacitive Charge	Qc	_	24	_	nC	I _F = 8A, dI/dt = 200A/μs V _R = 400V, T _J = +25°C
Total Capacitance	Ст		272 216 55		pF	$V_R = 0.1V$, $T_J = +25^{\circ}C$, $f = 1MHz$ $V_R = 1V$, $T_J = +25^{\circ}C$, $f = 1MHz$ $V_R = 40V$, $T_J = +25^{\circ}C$, $f = 1MHz$



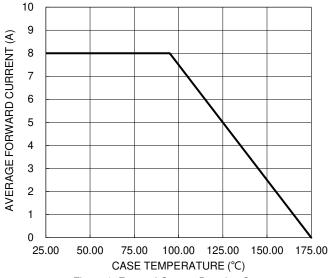


Figure 1. Forward Current Derating Curve

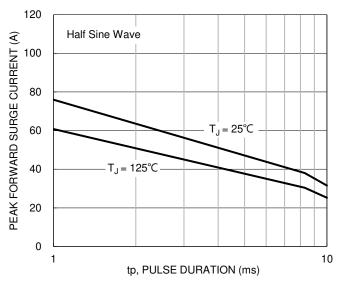
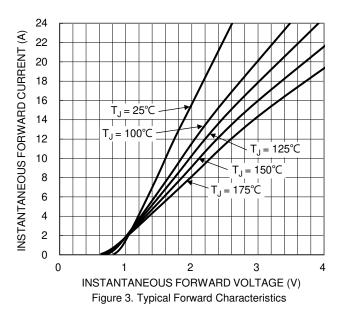
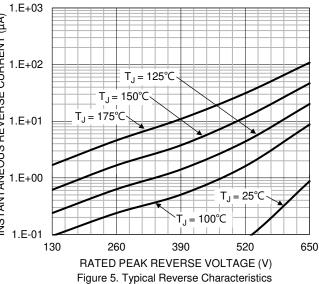


Figure 2. Non-Repetitive Peak Surge Forward Current



INSTANTANEOUS REVERSE CURRENT (µA) 1.E+02 $T_J = 125$ °C $T_J = 150^{\circ}C$ $T_{J} = 175^{\circ}C$ 1.E+01



1,000 $T_J = 25^{\circ}C$ f = 1MHzCAPACITANCE (pF) 100 10 0.1 10 100 REVERSE VOLTAGE (V)

Figure 4. Typical Junction Capacitance

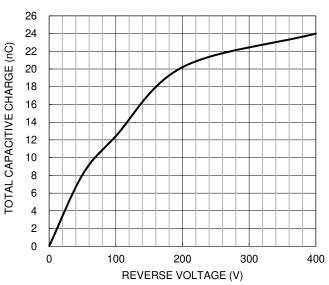


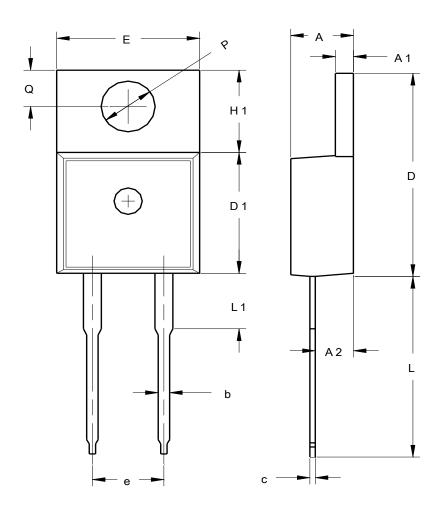
Figure 6. Typical Capacitive Charges



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO220AC (Type WX)



TO220AC (Type WX)				
Dim	Min	Тур		
Α	3.56	4.83		
A1	1.14	1.40		
A2	2.03	2.92		
b	0.51	1.14		
С	0.30	0.64		
D	14.40	15.20		
D1	8.26	9.28		
Е	9.65	10.67		
е	4.83	5.33		
H1	5.84	6.86		
	12.70	14.73		
L1		4.20		
PØ	3.53	4.09		
Q	2.54	3.43		
All Dimensions in mm				



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